

IC 1407 ACCREDIT



Far-Field Measurements and Characterization of the Cyclostationary Unintentional Stochastic Radiations from the Digital Electronic Device

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Outline

- Spatial localization of the pass between the source and the load on the PCB surface
- Characterization of the cyclostationary properties of the PCB pseudorandom emissions
- Characterization of the far-field pattern for the unintentional stochastic emissions of the PCB
- Parametric identification of the ultra wideband nearfield probes in time and frequency domains







Measurement setup

> Time-domain measurement system









Device under test

> Atlys Spartan-6 Training Board









Device under test



✓ Test signal: pseudo random bit sequence (PRBS)







Measurement setup



✓ Langer EMV-Technik RF-R 50-1 magnetic field probes
 ✓ Frequency band from 30 MHz up to 3 GHz









 $\checkmark \Delta = 3$ ns; $T = N \cdot \Delta$; N = 8192







> Autocorrelation function of the PRBS



$$R_{sT}(\tau) = \frac{1}{N\Delta} \int_{0}^{N\Delta} s_{T}(t) s_{T}(t-\tau) dt$$







> Averaged signal in the reference probe 10 Level [mV] 0 -10 0.3 0.2 0.4 0.5 0.6 0.7 0.8 0.9 Time [µs] $\mu_{X_m}[k] = \frac{L}{K} \sum_{i=0}^{(K/L)-1} X_m[k-jL]$

 $\checkmark L = N \cdot \Delta \cdot F$; K = 30L; F = 10 GSa/s – sampling frequency







Autocorrelation function of the reference probe's signal



Time [µs]

$$r_{X_m}[k] = \frac{1}{L} \sum_{l=0}^{L} \mu_{X_m}[l] \mu_{X_m}[l-k]$$







Autocorrelation function of the reference probe's signal









Cyclostationary analysis

> Periodic autocorrelation function









Cyclostationary analysis

> Cyclic autocorrelation function



$$R_X^l[\nu] = \frac{1}{L} \sum_{i=-(L-1)/2}^{(L-1)/2} \rho_X[i,\nu] e^{-j\frac{2\pi l\nu}{L}}$$

 $l \cdot F/L$ – cyclic frequency







Cyclostationary analysis

> Cyclic spectrum









Cross-correlation function of the reference probe's signal and PRBS



$$\rho_{SX_m}[n] = E\{S[k]X_m[k-n]\} = \frac{L}{K} \sum_{j=0}^{(K/L)-1} \sum_{k=0}^{L-1} S[k]X_m[k-n-jL]$$







≻Measurement grid



✓ 20 x 23 points ✓ 5 mm step ✓ H_X and H_Y polarization ✓ M = 20.23 = 460✓ $m = 1 \dots M$







Time evolution of the cross correlation function









Time evolution of the cross correlation function









> Measurement along the strip line















✓ Measurement points along the strip line







Delay of the cross correlation function



 $\rho_{X_{ref}X_m}[n] = E\{X_{ref}[k]X_m[k-n]\}$







Dependence on the distance between DUT and near-field probe











Vertical polarization Horizontal polarization



✓ distance 1...15 mm ✓ step size 1 mm







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Anechoic chamber



✓ Antenna R&S HL 562E
✓ 30 MHz ... 6 GHz
✓ Amplifier 30 dB







> Measured signal









Cross-correlation function of the antenna's signal and PRBS









Anechoic chamber

Vertical polarization Horizontal polarization





✓ distance 1 m







Vertical polarization Horizontal polarization





✓ distance 1 m







Anechoic chamber

Vertical polarization Horizontal polarization





✓ distance 3 m







Vertical polarization Horizontal polarization





✓ distance 3 m







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Measurement setup

Frequency-domain measurement system









S-parameters of Langer RF-R 50-1 probe









> Impulse response of the near-field probe



✓ RF-R 50-1 ✓ Ø 10 mm







> Step response of the near-field probe



✓ RF-R 50-1 ✓ Ø 10 mm







Measurement setup

> Time-domain measurement system













✓ Langer RF-R 50-1 ✓ Ø 10 mm ✓ Langer RF-R 3-2 ✓Ø 3 mm







> Step responses of the near-field probes



INSTITUTE

Frequency characteristic of the near-field probes









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